MIRA

Miniature Rubidium Atomic clock

MAIN FEATURES

- High frequency stability miniature Rubidium atomic clock
- High performance integrated function
- Holdover < 500ns within 24 hrs at fix temperature
- PPS disciplining
- Low SWaP (Size, Weight, Power) features.
- Low profile, reduced height to 16mm, ultra-portable packaging
- RoHS and REACH compliant
- Operating temperature: -20°C to +70°C (standard version),
 -40°C to +80°C (Ruggedized version)



*Enclosure appearance subject to change



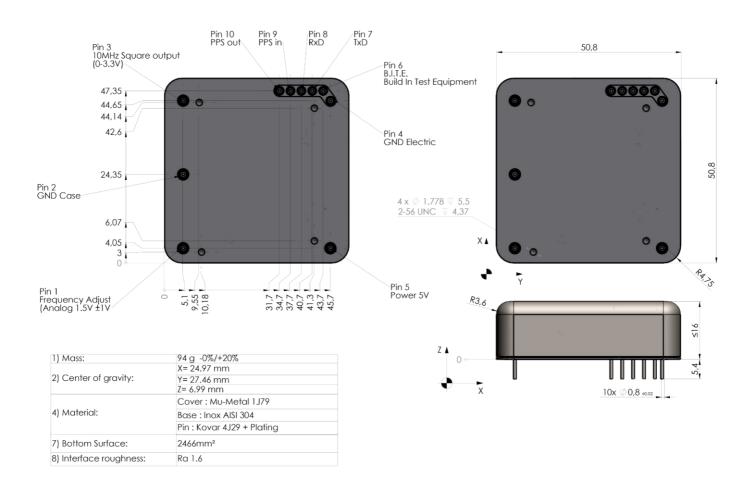
MIRA

Micro Rubidium Atomic clock

SOLUTION

- Standard clock for industrial applications, Ruggedized clock for toughest applications.
- High stability frequency source.
- Telecom & mobile network synchronization.
- Military airborne, ground, mobile and unmanned radio communications.
- Oil & gas sensor-based exploration.
- · Instrumentation.
- Portable & battery-sensitive applications.
- · GPS/GNSS-based applications.

Package: all dimensions in mm



TECHNICAL SPECIFICATIONS

ELECTRICAL

Туре	MIRA	
1360	Standard version	Ruggedized version
Frequency	10 MHz	Ruggedized version
Frequency change within operating temperature	1E-10 peak-to-peak, <5E-12 / °C (TBC)	1E-10 peak-to-peak, <5E-12 / °C (TBC)
range	over -20°C to +70°C	over -40°C to +80°C
Linear drift measured over minimum 14 days After 3	0Vei -20 C t0 +70 C	
months operations*	ZEE 12 / dov	
·	≤5E-12 / day	
Short term stability*		
1sec	≤ 4E-11	
10 sec	≤1.3E-11	
100 sec	≤ 4E-12	
1000 sec	≤3E-12 (typical)	
10 000 sec	≤5E-12 (typical)	
Phase noise (10 MHz) in dBc/Hz*		
1 Hz	≤ -70	
10 Hz	≤ -97	
10 HZ 100 Hz	≤ -120	
1000 Hz	≤-135	
	≤-135 ≤-140	
10000 Hz	<u> </u>	
Frequency retrace*	<1E-10	
Warm-up time	Lock < 2 minutes at over the full temperature range	
Analog frequency adjustment (+1.5V ±1V)		
For stable operation, an external voltage shall be	±5.4E-9 (±20%) peak to peak	
applied (cf. the manual of the MIRA for electrical		
scheme)		
Digital frequency adjustment range with serial RS-	Fine: ±8.1E-9 (resolution 2.5E-13) ±20%	
232 port.	Coarse: ±1E-7 (resolution1.24E-9)	
Output level	Square wave 0-3V	
Spurious f _o ± 100kHz	<-80dBc	
Supply voltage	5V	
Max Power Supply Ripple	< 50 mV peak to peak (from 1Hz to 1 MHz frequency band)	
Input power @ 25°C	0.5W steady state	
	2.5W start-up	
	1.5W steady state, using high performance fund	ction
	5W start up, using high performance function	
DITE Indicator	5.7 Start ap, daining riight portor manoc function	
B.I.T.E. Indicator	2.71/(
	Alarm > 2.7V (unloaded)	
No Alarm	< 0.4V	
Communication with serial RS-232 port	Rx and Tx signals are idle at low level (to inve	rt polarity use option COMSTD)

ENVIRONMENTAL**

Туре	MIRA		
Magnetic field sensitivity	< 1E-10/ Gauss, range [-1;+1] Gauss	< 1E-10/ Gauss, range [-1;+1] Gauss	
StorageTemperature	- 55°C to + 105°C	- 55°C to + 105°C	
Operating Temperature	- 20°C to + 70°C	- 40°C to + 80°C	
	(maximum temperature of the thermal ch	(maximum temperature of the thermal chamber with air flow around unit)	
Altitude	Meets MIL-STD-810H, Method 500.6 40 000 ft	Max 70,000 ft	
Vibration	MIL-STD-810H, Method 514.8 annex C 4 gRMS	7.7 gRMS	
Shocks	MIL-STD-202 30g, 11 ms, half sinus	50g, 11ms, half sinus	
Acceleration		Load factor of 12g during 1mn in any axis or direction	
Humidity	MIL-STD-810H, Method 507.6	DO160G, section 6	
	35°C, 95% relative humidity	65°C, 95%	
g-tip-over test	2E-10/g on worst sensitive axis	2E-10/g on worst sensitive axis	
MTBF	MIL-HDBK-217F Notice 2 >150 000 h Ground Begnin at 40°C	Same to standard + >40 000 FH for ARW50 environment	

 $[\]hbox{``in stable temperature, gravity, pressure and magnetic field conditions'}\\$

 $^{{}^{\}star\star}pass/fail\,criteria = no\,loss\,of\,lock.\,Each\,one\,tested\,independently\,(no\,combination\,of\,environmental\,tests)$

DISCIPLINING

Туре	MIRA
PPSREF Level	CMOS 0 - 3V
PPSOUT Output Level Voltage Current	CMOS 0 - 3V 20mA sink/source (50 Ω serial resistor)
PPSOUT Duty cycle programmable pulse width	100 ns/stepfrom 0 to 1 s
PPSOUT to PPSREF Sync Error due to hardware delay	<50 ns No PPSRef noise, ±1°C temp fluctuations
PPSOUT to PPSREF programmable delay	100ns/step from 0 to 1 s
PPSOUT Holdover Time Stability After one day disciplining	< 500ns / 24 hr (Target)
Temperature window	Within±0.2°C
Digital loop time constant	10s to 100,000s

PHYSICAL

Туре	MIRA
Size	50.8 x 50.8 x 16 mm (+/- 0.1mm) 2" x 2" x 0.63"
Weight	94 g 0/+20% 3.98 oz max
Volume	< 42 cc

MORE ON APPLICATIONS

The MIRA has been designed to meet the highest requirements necessary to support various levels of military and commercial applications.



GNSS operation through interference Low Earth Orbit satellite missions





Military communication systems Key Infrastructure Emergency Vehicles Radars

Aircraft and UAVs



Secured telecom

Underwater geological applications

Autonomous cars

Aircrafts

COMMERCIAL

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